

## **RXO2213S**

The RXO2213S is a radiation tolerant XO housed in a 22 x 13 mm low profile, hermetically sealed package. This XO offers precise frequency stability of  $\pm 15$  ppm. Engineered for range for space missions requiring exceptional resistance to demanding environments, the RXO2213S ensures robust performance under challenging conditions. The oscillator is available with a short lead time, providing a reliable solution for time-sensitive applications.

#### **Features**

- TID limit of 100 krad and SEL free up to LET 62 MeV.cm<sup>2</sup>/mg
- Hermetically sealed package
- Frequency range:0.256Hz to 72 MHz
- Supply voltage: 2.5, 3.3, 5.0 V
- FvT: ±50 ppm over -55 to 125°C
- Manufactured in accordance with MIL-PRF-55310 Class 2, level S

## **Applications**

- Space applications such as clocks
- Gyroscopes and Frequency Generation Units (FGU)

# 22 x 13 mm



#### **Environmental Conditions**

Parameter	Test Conditions/Description	Min.	Тур.	Max.	Unit
Operating temperature (To)	Option A Option B	-25 -55		85 125	°C
Storage temperature (Ts)		-55		125	°C

## **Frequency Characteristics**

Parameter	Test Conditions/Description	Min.	Тур.	Max.	Unit
Initial frequency accuracy	@ 25°C			±15	ppm
Frequency stability over temperature (FvT)	Option A: -25 to 85°C Option B: -55 to 125°C			±25 ±50	ppm
Supply voltage stability	±5% tolerance			±2	ppm
Ageing	Per year @ 70°C			±3	ppm
				10	ms

## **Electrical Interface**

Parameter	Test Conditions/Description	Min.	Тур.	Max.	Unit
Power supply (Vcc)	±5% tolerance		2.5, 3.3, 5.0		V
Input current <sup>1</sup>	No load		35		mA

## **Output Characteristics HCMOS<sup>2</sup>**

Parameter	Test Conditions/Description	Min.	Тур.	Max.	Unit
Nominal frequency (Fn)	HCMOS output option A	0.256		52.5	MHz
	HCMOS output option B	0.00005		72	
Output voltage (Vol)1	15 pF load			10% Vcc	V
Output voltage (Voн)¹	15 pF load	90% Vcc			V
Duty cycle <sup>1</sup>	@50% Vcc	40		60	%
Rise time / Fall time <sup>1</sup>	10 % to 90% Vcc			10	ns

 $<sup>^{\</sup>scriptsize 1}$  Over temperature range.

 $<sup>^{\</sup>rm 2}$  Transistor Transistor Logic (TTL) output option available on request.



## **Environmental Specifications**

Screening Operation	Requirements and Condition			
Non-destructive bond pull	MIL-STD-883, method 2023			
Internal visual	MIL-STD-883, method 2017 and method 2032			
Stabilisation bake (prior to seal)	MIL-STD-883, method 1008, condition C (+150°C), 48 hours minimum			
Thermal shock	MIL-STD-883, method 1011, condition A			
Temperature cycling	MIL-STD-883, method 1010, condition C			
Constant acceleration	MIL-STD-883, method 2001, condition A, Y1 only (5000 g's)			
Seal (fine and gross leak)	MIL-STD-883, method 1014:	Fine leak Test condition A1, A2, or B	Fine leak Test condition B2 or B3	
Particle impact noise detection (PIND)	MIL-STD-883, method 2020, condition A			
Electrical test	Nominal and extreme supply voltages, specified load, 23°C and temperature extremes, record all test parameters by serial number			
Burn-in (load)	115°C, nominal supply voltage and burn-in load, 440 hours minimum			
Radiographic	MIL-STD-883, method 2012			
External Visual	MIL-STD-883, method 2009			

## **Model Outline and Pin Connections**

Parameter	Requirements / Condition
Package size	L x W: 22 x 12.65 mm nom. H = 4.8 mm max.
Net weight	15 g typ.

